

## PTLC03D-B – ESD Protection Diode

### Feature

- 350 Watts peak pulse power (8/20 $\mu$ s)
- Bidirectional configurations
- Protect one power line
- Solid state silicon-avalanche technology
- Low operating voltage
- Low leakage current
- Low Capacitance: 1.0 pF Typical
- IEC61000-4-2 (ESD)  $\pm$ 30kV (Air),  $\pm$ 30kV (Contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning): 20A (8/20 $\mu$ s)



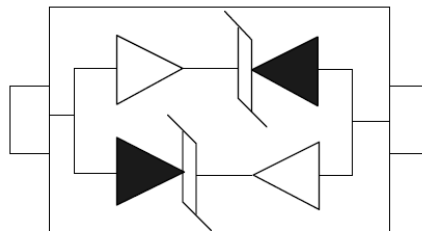
### Applications

- Ethernet - 10/100/1000 Base T
- Cellular Phones
- Handheld - Wireless Systems
- Personal Digital Assistant (PDA)
- USB Interface

### Mechanical Data

- SOD323 package
- Molding compound flammability rating: UL94 V-0
- Tape and Reel Packaging
- RoHS/WEEE Compliant

### Schematic and PIN Configuration



SOD-323

### Maximum Rating

Parameter	Symbol	Limit	Unit
IEC61000-4-2 ESD Voltage – Air Mode	$V_{ESD}^{(1)}$	$\pm$ 30	kV
IEC61000-4-2 ESD Voltage – Contact Mode		$\pm$ 30	
Peak Pulse Power	$P_{PP}^{(2)}$	350	W
Peak Pulse Current	$I_{PP}^{(2)}$	20	A
Maximum Lead Solder Temperature (10 seconds duration)	$T_L$	260	$^{\circ}$ C
Junction Temperature	$T_J$	-55~150	$^{\circ}$ C
Storage Temperature Range	$T_{stg}$	-55~150	$^{\circ}$ C

Note:

1. Device stressed with ten non-repetitive ESD pulses.
2. Non-repetitive current pulse 8/20 $\mu$ s exponential decay waveform according to IEC61000-4-5.
3. All ratings are measured at environmental temperature of  $T_A = 25^{\circ}$ C unless otherwise noted.

## PTLC03D-B – ESD Protection Diode

### Electrical Characteristics

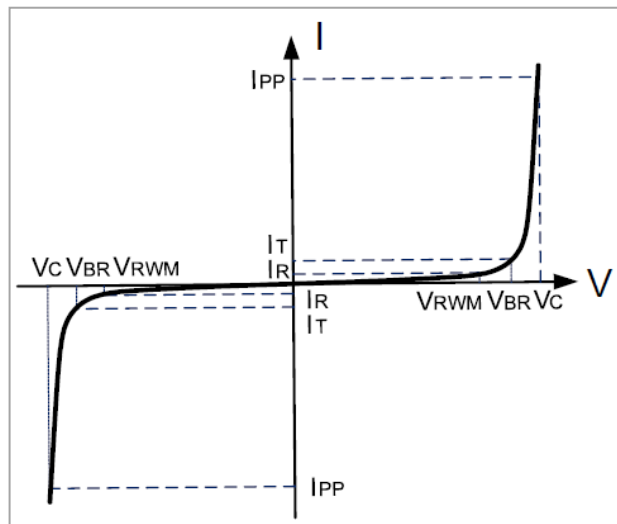
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Stand-off Voltage	$V_{RWM}^{(1)}$				3.3	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	4.0			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3\text{V}$			1	$\mu\text{A}$
Clamping Voltage	$V_C^{(2)}$	$I_{PP} = 20\text{A}$			18	V
Junction Capacitance	$C_J$	$V_R = 0\text{V}, f = 1\text{MHz}$		1.0	1.5	pF

Note:

1. Other voltages available upon request.
2. Non-repetitive current pulse 8/20 $\mu\text{s}$  exponential decay waveform according to IEC61000-4-5.
3. All ratings are measured at environmental temperature of  $T_A = 25^\circ\text{C}$  unless otherwise noted.

### Electrical Parameters

Symbol	Parameter
$V_C$	Clamping Voltage @ $I_{PP}$
$I_{PP}$	Reverse Peak Pulse Current
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{RWM}$	Working Peak Reverse Voltage



## PTLC03D-B – ESD Protection Diode

### Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

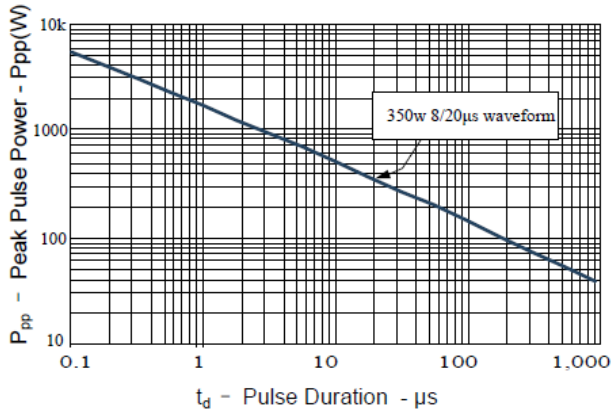


Figure 2: Power Derating Curve

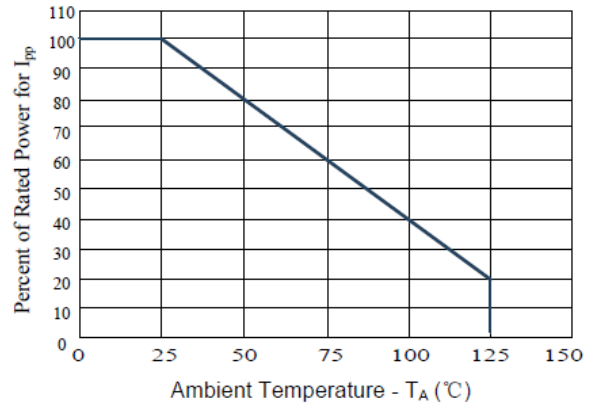


Figure 3: Pulse Waveform

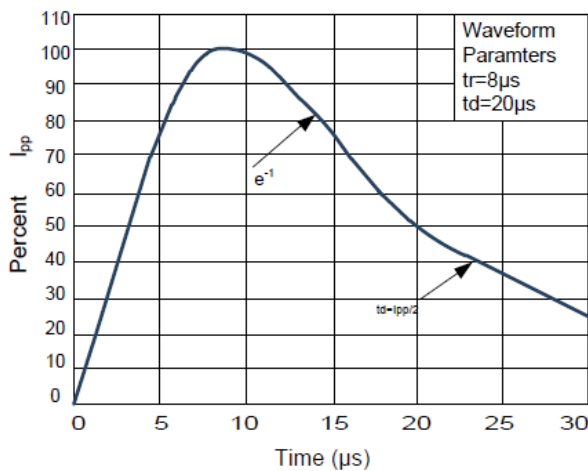
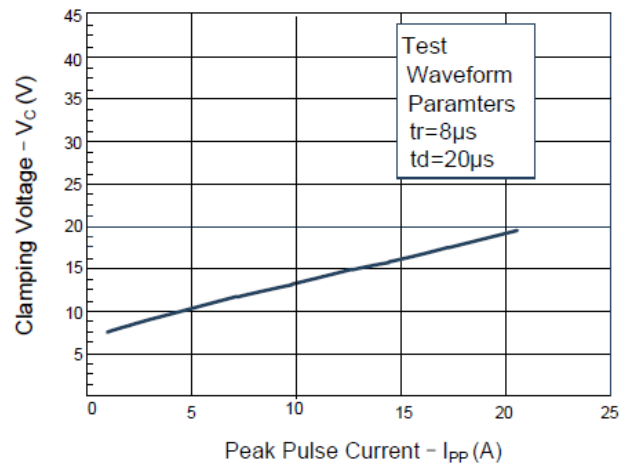
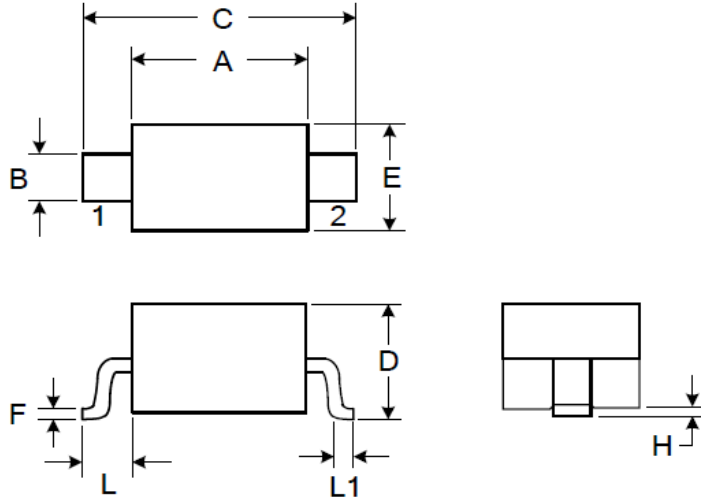


Figure 4: Clamping Voltage vs. Ipp



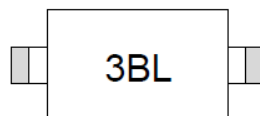
## PTLC03D-B – ESD Protection Diode

### SOD323 Package Outline Dimensions



Symbol	Dimensions (mm)		Dimensions (inch)	
	Min	Max	Min	Max
A	1.600	1.800	0.063	0.071
B	0.250	0.350	0.010	0.014
C	2.500	2.700	0.098	0.106
D		1.000		0.039
E	1.200	1.400	0.047	0.055
F	0.080	0.150	0.003	0.006
L	0.475 Ref.		0.019 Ref.	
L1	0.250	0.400	0.010	0.016
H		0.100		0.004

### Marking



### Packaging Information

Order Code	Packaging	Reel Size	PCS/Reel
PTLC03D-B	SOD323	7 inch	3,000